

## QUAD BILATERAL SWITCHES

### FEATURES

- Low "ON" resistance:  
90 Ω (typ.) at  $V_{CC} = 4.5\text{ V}$   
80 Ω (typ.) at  $V_{CC} = 6.0\text{ V}$   
65 Ω (typ.) at  $V_{CC} = 9.0\text{ V}$
- Individual switch controls
- Typical "break before make" built in
- Output capability: non-standard
- I<sup>2</sup>C category: SSI

### GENERAL DESCRIPTION

The 74HC/HCT4016 are high-speed Si-gate CMOS devices and are pin compatible with the "4016" of the "4000B" series. They are specified in compliance with JEDEC standard no. 7A.

The 74HC/HCT4016 have four independent analog switches (transmission gates).

Each switch has two input/output terminals ( $Y_n$ ,  $Z_n$ ) and an active HIGH enable input ( $E_n$ ). When  $E_n$  is connected to  $V_{CC}$ , a low bidirectional path between  $Y_n$  and  $Z_n$  is established (ON condition). When  $E_n$  is connected to ground (GND), the switch is disabled and a high impedance between  $Y_n$  and  $Z_n$  is established (OFF condition).

Current through a switch will not cause additional  $V_{CC}$  current provided the voltage at the terminals of the switch is maintained within the supply voltage range:  $V_{CC} \geq (V_Y, V_Z) \geq \text{GND}$ . Inputs  $Y_n$  and  $Z_n$  are electrically equivalent terminals.

SYMBOL	PARAMETER	CONDITIONS	TYPICAL		UNIT
			HC	HCT	
$t_{PZH}/t_{PZL}$	turn "ON" time $E_n$ to $V_{Os}$	$C_L = 15\text{ pF}$ $R_L = 1\text{ k}\Omega$ $V_{CC} = 5\text{ V}$	16	17	ns
$t_{PHZ}/t_{PLZ}$	turn "OFF" time $E_n$ to $V_{Os}$		14	20	ns
$C_I$	input capacitance		3.5	3.5	pF
$C_{PD}$	power dissipation capacitance per switch	notes 1 and 2	12	12	pF
$C_S$	max. switch capacitance		5	5	pF

GND = 0 V;  $T_{amb} = 25^\circ\text{C}$ ;  $t_r = t_f = 6\text{ ns}$

### Notes

1.  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu\text{W}$ ):

$$P_D = C_{PD} \times V_{CC}^2 \times f_i + \sum \{(C_L + C_S) \times V_{CC}^2 \times f_o\}$$

$f_i$  = input frequency in MHz  
 $f_o$  = output frequency in MHz  
 $\sum \{(C_L + C_S) \times V_{CC}^2 \times f_o\}$  = sum of outputs

$C_L$  = output load capacitance in pF  
 $C_S$  = max. switch capacitance in pF  
 $V_{CC}$  = supply voltage in V

2. For HC the condition is  $V_I = \text{GND to } V_{CC}$   
For HCT the condition is  $V_I = \text{GND to } V_{CC} - 1.5\text{ V}$

### ORDERING INFORMATION/PACKAGE OUTLINES

PC74HC/HCT4016P: 14-lead DIL; plastic (SOT-27).

PC74HC/HCT4016T: 14-lead mini-pack; plastic (SO-14; SOT-108A).

### PIN DESCRIPTION

PIN NO.	SYMBOL	NAME AND FUNCTION
1, 4, 8, 11	$Y_0$ to $Y_3$	independent inputs/outputs
7	GND	ground (0 V)
2, 3, 9, 10	$Z_0$ to $Z_3$	independent inputs/outputs
13, 5, 6, 12	$E_0$ to $E_3$	enable inputs (active HIGH)
14	$V_{CC}$	positive supply voltage

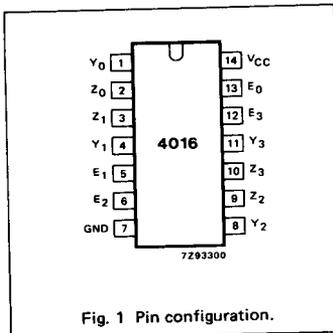


Fig. 1 Pin configuration.

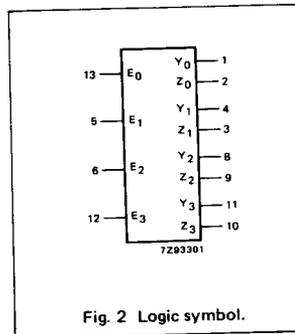


Fig. 2 Logic symbol.

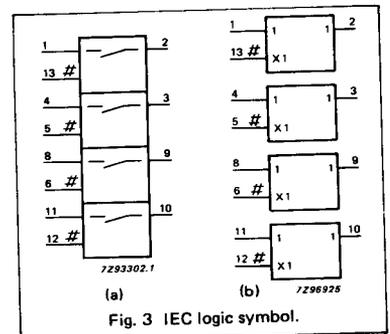


Fig. 3 IEC logic symbol.

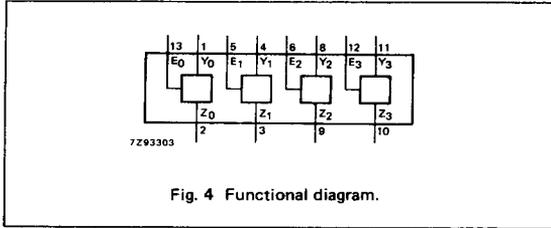


Fig. 4 Functional diagram.

**APPLICATIONS**

- Signal gating
- Modulation
- Demodulation
- Chopper

**FUNCTION TABLE**

INPUT $E_n$	CHANNEL IMPEDANCE
L	high
H	low

H = HIGH voltage level  
L = LOW voltage level

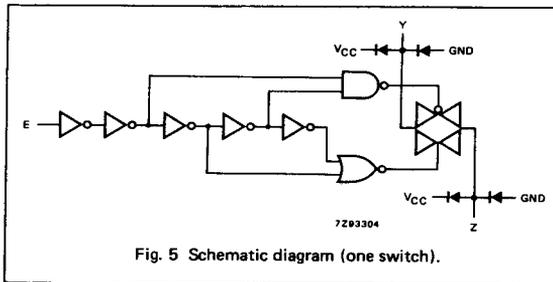


Fig. 5 Schematic diagram (one switch).

**RATINGS**

Limiting values in accordance with the Absolute Maximum System (IEC 134)

Voltages are referenced to GND (ground = 0 V)

SYMBOL	PARAMETER	MIN.	MAX.	UNIT	CONDITIONS
$V_{CC}$	DC supply voltage	-0.5	+11.0	V	
$\pm I_{IK}$	DC digital input diode current		20	mA	for $V_I < -0.5$ V or $V_I > V_{CC} + 0.5$ V
$\pm I_{SK}$	DC switch diode current		20	mA	for $V_S < -0.5$ V or $V_S > V_{CC} + 0.5$ V
$\pm I_S$	DC switch current		25	mA	for $-0.5$ V $< V_S < V_{CC} + 0.5$ V
$\pm I_{CC}$ ; $\pm I_{GND}$	DC $V_{CC}$ or GND current		50	mA	
$T_{stg}$	storage temperature range	-65	+150	°C	
$P_{tot}$	power dissipation per package				for temperature range: -40 to +125 °C 74HC/HCT
	plastic DIL		750	mW	above +70 °C: derate linearly with 12 mW/K
	plastic mini-pack (SO)		500	mW	above +70 °C: derate linearly with 8 mW/K
$P_S$	power dissipation per switch		100	mW	

**RECOMMENDED OPERATING CONDITIONS**

SYMBOL	PARAMETER	74HC			74HCT			UNIT	CONDITIONS
		min.	typ.	max.	min.	typ.	max.		
$V_{CC}$	DC supply voltage	2.0	5.0	10.0	4.5	5.0	5.5	V	
$V_I$	DC input voltage range	GND		$V_{CC}$	GND		$V_{CC}$	V	
$V_S$	DC switch voltage range	GND		$V_{CC}$	GND		$V_{CC}$	V	
$T_{amb}$	operating ambient temperature range	-40		+85	-40		+85	°C	see DC and AC CHARACTERISTICS
$T_{amb}$	operating ambient temperature range	-40		+125	-40		+125	°C	
$t_r, t_f$	input rise and fall times		6.0	1000 500 400 250		6.0	500	ns	$V_{CC} = 2.0$ V $V_{CC} = 4.5$ V $V_{CC} = 6.0$ V $V_{CC} = 10.0$ V

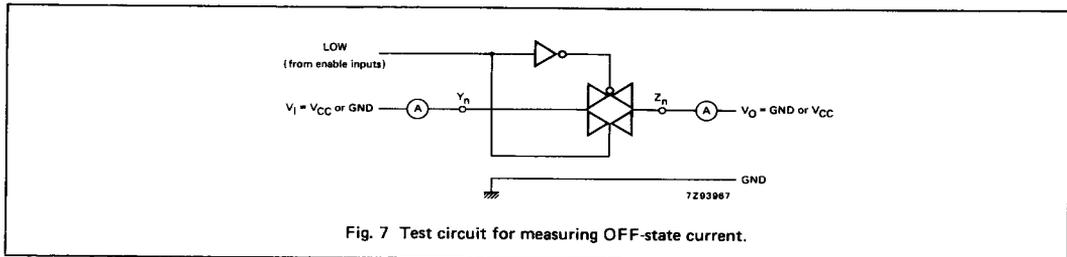
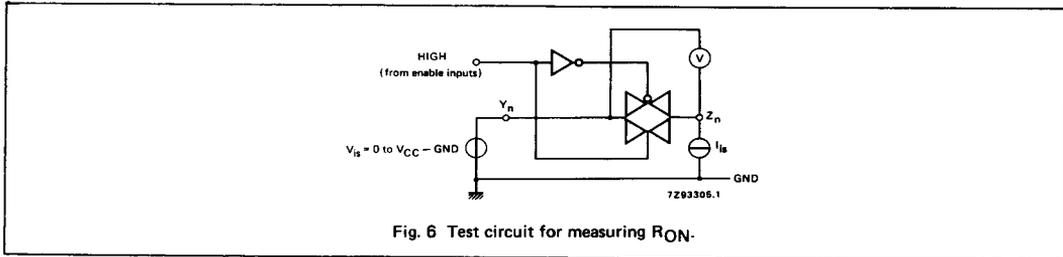
**DC CHARACTERISTICS FOR 74HC/HCT**

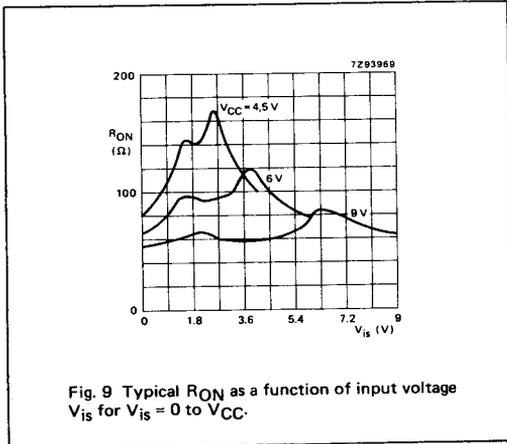
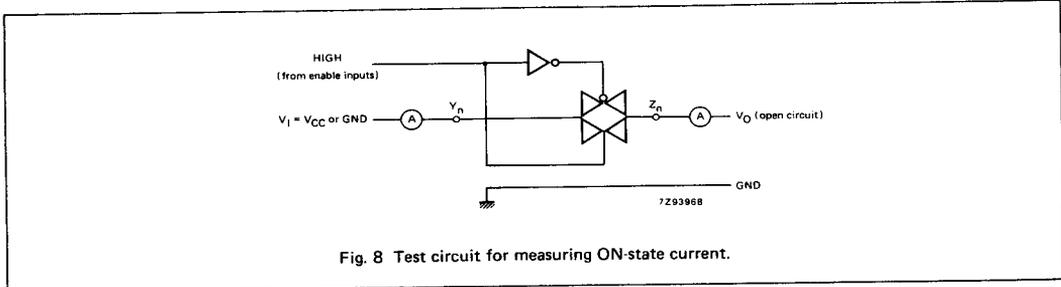
For 74HC:  $V_{CC} = 2.0, 4.5, 6.0$  and  $9.0$  V  
For 74HCT:  $V_{CC} = 4.5$  V

SYMBOL	PARAMETER	$T_{amb}$ (°C)						UNIT	TEST CONDITIONS				
		74HC/HCT							$V_{CC}$ V	$I_S$ $\mu A$	$V_{is}$	$V_I$	
		+25			-40 to +85		-40 to +125						
		min.	typ.	max.	min.	max.	min.						max.
$R_{ON}$	ON resistance (peak)		160 120 85	320 240 170		400 300 213		480 360 255	$\Omega$ $\Omega$ $\Omega$	2.0 4.5 6.0 9.0	100 1000 1000 1000	$V_{CC}$ to GND	$V_{IH}$ or $V_{IL}$
$R_{ON}$	ON resistance (rail)		160 80 70 60	— 160 140 120		— 200 175 150		— 240 210 180	$\Omega$ $\Omega$ $\Omega$ $\Omega$	2.0 4.5 6.0 9.0	100 1000 1000 1000	GND	$V_{IH}$ or $V_{IL}$
$R_{ON}$	ON resistance (rail)		170 90 80 65	— 180 160 135		— 225 200 170		— 270 240 205	$\Omega$ $\Omega$ $\Omega$ $\Omega$	2.0 4.5 6.0 9.0	100 1000 1000 1000	$V_{CC}$	$V_{IH}$ or $V_{IL}$
$\Delta R_{ON}$	maximum $\Delta R_{ON}$ resistance between any two channels		16 12 9						$\Omega$ $\Omega$ $\Omega$ $\Omega$	2.0 4.5 6.0 9.0		$V_{CC}$ to GND	$V_{IH}$ or $V_{IL}$

**Notes to DC characteristics**

1. At supply voltages approaching 2.0 V the analog switch ON-resistance becomes extremely non-linear. Therefore it is recommended that these devices be used to transmit digital signals only, when using these supply voltages.
2. For test circuit measuring  $R_{ON}$  see Fig. 6.





**DC CHARACTERISTICS FOR 74HC**

Voltages are referenced to GND (ground = 0 V)

SYMBOL	PARAMETER	T <sub>amb</sub> (°C)								UNIT	TEST CONDITIONS		
		74HC									V <sub>CC</sub> V	V <sub>I</sub>	OTHER
		+25			-40 to +85		-40 to +125						
		min.	typ.	max.	min.	max.	min.	max.					
V <sub>IH</sub>	HIGH level input voltage	1.5 3.15 4.2 6.3	1.2 2.4 3.2 4.3		1.5 3.15 4.2 6.3		1.5 3.15 4.2 6.3		V	2.0 4.5 6.0 9.0			
V <sub>IL</sub>	LOW level input voltage		0.8 2.1 2.8 4.3	0.50 1.35 1.80 2.70		0.50 1.35 1.80 2.70		0.50 1.35 1.80 2.70	V	2.0 4.5 6.0 9.0			
±I <sub>I</sub>	input leakage current			0.1 0.2		1.0 2.0		1.0 2.0	μA	6.0 10.0	V <sub>CC</sub> or GND		
±I <sub>S</sub>	analog switch OFF-state current per channel			0.1		1.0		1.0	μA	10.0	V <sub>IH</sub> or V <sub>IL</sub>	V <sub>S</sub>   = V <sub>CC</sub> - GND (see Fig. 7)	
±I <sub>S</sub>	analog switch ON-state current			0.1		1.0		1.0	μA	10.0	V <sub>IH</sub> or V <sub>IL</sub>	V <sub>S</sub>   = V <sub>CC</sub> - GND (see Fig. 8)	
I <sub>CC</sub>	quiescent supply current			2.0 4.0		20.0 40.0		40.0 80.0	μA	6.0 10.0	V <sub>CC</sub> or GND	V <sub>is</sub> = GND or V <sub>CC</sub> ; V <sub>os</sub> = V <sub>CC</sub> or GND	

**AC CHARACTERISTICS FOR 74HC**

GND = 0 V; t<sub>r</sub> = t<sub>f</sub> = 6 ns; C<sub>L</sub> = 50 pF

SYMBOL	PARAMETER	T <sub>amb</sub> (°C)								UNIT	TEST CONDITIONS	
		74HC									V <sub>CC</sub> V	OTHER
		+ 25			-40 to +85		-40 to +125					
		min.	typ.	max.	min.	max.	min.	max.				
t <sub>PHL</sub> / t <sub>PLH</sub>	propagation delay V <sub>is</sub> to V <sub>os</sub>		17 6 5 4	60 12 10 8		75 15 13 10		90 18 15 12	ns	2.0 4.5 6.0 9.0	R <sub>L</sub> = ∞; C <sub>L</sub> = 50 pF (see Fig. 16)	
t <sub>pZH</sub> / t <sub>pZL</sub>	turn "ON" time E <sub>n</sub> to V <sub>os</sub>		52 19 15 11	190 38 32 28		240 48 41 35		235 57 48 42	ns	2.0 4.5 6.0 9.0	R <sub>L</sub> = 1 kΩ; C <sub>L</sub> = 50 pF (see Figs 17 and 18)	
t <sub>pHZ</sub> / t <sub>PLZ</sub>	turn "OFF" time E <sub>n</sub> to V <sub>os</sub>		47 17 14 13	145 29 25 22		180 36 31 28		220 44 38 33	ns	2.0 4.5 6.0 9.0	R <sub>L</sub> = 1 kΩ; C <sub>L</sub> = 50 pF (see Figs 17 and 18)	

## DC CHARACTERISTICS FOR 74HCT

Voltages are referenced to GND (ground = 0 V)

SYMBOL	PARAMETER	T <sub>amb</sub> (°C)						UNIT	TEST CONDITIONS			
		74HCT							V <sub>CC</sub> V	V <sub>I</sub>	OTHER	
		+25			-40 to +85		-40 to +125					
		min.	typ.	max.	min.	max.	min.					max.
V <sub>IH</sub>	HIGH level input voltage	2.0	1.6		2.0		2.0		V	4.5 to 5.5		
V <sub>IL</sub>	LOW level input voltage		1.2	0.8		0.8		0.8	V	4.5 to 5.5		
±I <sub>I</sub>	input leakage current			0.1		1.0		1.0	μA	5.5	V <sub>CC</sub> or GND	
±I <sub>S</sub>	analog switch OFF-state current per channel			0.1		1.0		1.0	μA	5.5	V <sub>IH</sub> or V <sub>IL</sub>	V <sub>S</sub>   = V <sub>CC</sub> - GND (see Fig. 7)
±I <sub>S</sub>	analog switch ON-state current			0.1		1.0		1.0	μA	5.5	V <sub>IH</sub> or V <sub>IL</sub>	V <sub>S</sub>   = V <sub>CC</sub> - GND (see Fig. 8)
I <sub>CC</sub>	quiescent supply current			2.0		20.0		40.0	μA	4.5 to 5.5	V <sub>CC</sub> or GND	V <sub>is</sub> = GND or V <sub>CC</sub> ; V <sub>os</sub> = V <sub>CC</sub> or GND
ΔI <sub>CC</sub>	additional quiescent supply current per input pin for unit load coefficient is 1 (note 1)		100	360		450		490	μA	4.5 to 5.5	V <sub>CC</sub> -2.1V	other inputs at V <sub>CC</sub> or GND

## Note

1. The value of additional quiescent supply current (ΔI<sub>CC</sub>) for a unit load of 1 is given here.  
To determine ΔI<sub>CC</sub> per input, multiply this value by the unit load coefficient shown in the table below.

INPUT	UNIT LOAD COEFFICIENT
E <sub>n</sub>	1.00

**AC CHARACTERISTICS FOR 74HCT**

GND = 0 V;  $t_r = t_f = 6$  ns;  $C_L = 50$  pF

SYMBOL	PARAMETER	T <sub>amb</sub> (°C)						UNIT	TEST CONDITIONS		
		74HCT							V <sub>CC</sub> V	OTHER	
		+25			-40 to +85		-40 to +125				
		min.	typ.	max.	min.	max.	min.				max.
t <sub>PHL</sub> / t <sub>PLH</sub>	propagation delay V <sub>is</sub> to V <sub>Os</sub>		6	12		15		18	ns	4.5	R <sub>L</sub> = ∞; C <sub>L</sub> = 50 pF (see Fig. 16)
t <sub>PZH</sub>	turn "ON" time E <sub>N</sub> to V <sub>Os</sub>		19	35		44		53	ns	4.5	R <sub>L</sub> = 1 kΩ; C <sub>L</sub> = 50 pF (see Figs 17 and 18)
t <sub>PZL</sub>	turn "ON" time E <sub>N</sub> to V <sub>Os</sub>		20	35		44		53	ns	4.5	R <sub>L</sub> = 1 kΩ; C <sub>L</sub> = 50 pF (see Figs 17 and 18)
t <sub>PHZ</sub> / t <sub>PLZ</sub>	turn "OFF" time E <sub>N</sub> to V <sub>Os</sub>		23	35		44		53	ns	4.5	R <sub>L</sub> = 1 kΩ; C <sub>L</sub> = 50 pF (see Figs 17 and 18)

**ADDITIONAL AC CHARACTERISTICS FOR 74HC/HCT**

Recommended conditions and typical values

GND = 0 V;  $t_r = t_f = 6$  ns

SYMBOL	PARAMETER	typ.	UNIT	V <sub>CC</sub> V	V <sub>is(p-p)</sub> V	CONDITIONS
	sine-wave distortion f = 1 kHz	0.80 0.40	% %	4.5 9.0	4.0 8.0	R <sub>L</sub> = 10 kΩ; C <sub>L</sub> = 50 pF (see Fig. 14)
	sine-wave distortion f = 10 kHz	2.40 1.20	% %	4.5 9.0	4.0 8.0	R <sub>L</sub> = 10 kΩ; C <sub>L</sub> = 50 pF (see Fig. 14)
	switch "OFF" signal feed-through	-50 -50	dB dB	4.5 9.0	note 1	R <sub>L</sub> = 600 Ω; C <sub>L</sub> = 50 pF; f = 1 MHz (see Figs 10 and 15)
	crosstalk between any two switches	-60 -60	dB dB	4.5 9.0	note 1	R <sub>L</sub> = 600 Ω; C <sub>L</sub> = 50 pF; f = 1 MHz (see Fig. 12)
V <sub>(p-p)</sub>	crosstalk voltage between enable or address input to any switch (peak-to-peak value)	110 220	mV mV	4.5 9.0		R <sub>L</sub> = 600 Ω; C <sub>L</sub> = 50 pF; f = 1 MHz (E <sub>N</sub> , square wave between V <sub>CC</sub> and GND, t <sub>r</sub> = t <sub>f</sub> = 6 ns) (see Fig. 13)
f <sub>max</sub>	minimum frequency response (-3dB)	150 160	MHz MHz	4.5 9.0	note 2	R <sub>L</sub> = 50 Ω; C <sub>L</sub> = 10 pF (see Figs 11 and 14)
C <sub>S</sub>	maximum switch capacitance	5	pF			

**Notes to AC characteristics**

**General note**

V<sub>is</sub> is the input voltage at a Y<sub>n</sub> or Z<sub>n</sub> terminal, whichever is assigned as an input.  
V<sub>Os</sub> is the output voltage at a Y<sub>n</sub> or Z<sub>n</sub> terminal, whichever is assigned as an output.

**Notes**

1. Adjust input voltage V<sub>is</sub> to 0 dBm level (0 dBm = 1 mW into 600 Ω).
2. Adjust input voltage V<sub>is</sub> to 0 dBm level at V<sub>Os</sub> for 1 MHz (0 dBm = 1 mW into 50 Ω).

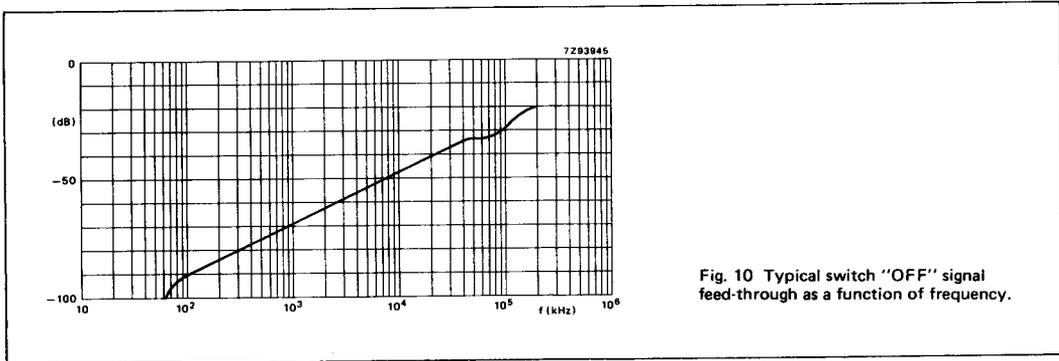
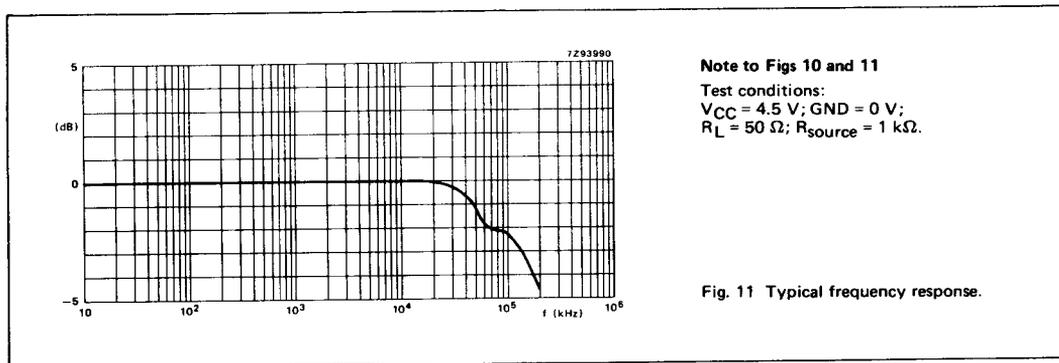


Fig. 10 Typical switch "OFF" signal feed-through as a function of frequency.



Note to Figs 10 and 11

Test conditions:  
V<sub>CC</sub> = 4.5 V; GND = 0 V;  
R<sub>L</sub> = 50 Ω; R<sub>source</sub> = 1 kΩ.

Fig. 11 Typical frequency response.

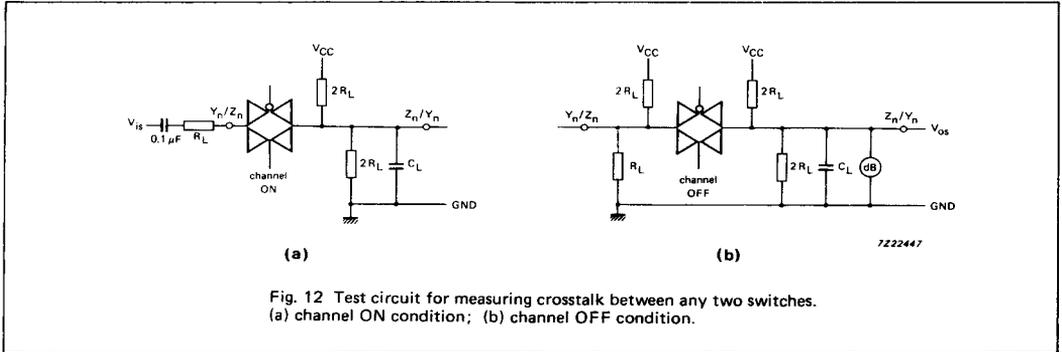


Fig. 12 Test circuit for measuring crosstalk between any two switches. (a) channel ON condition; (b) channel OFF condition.

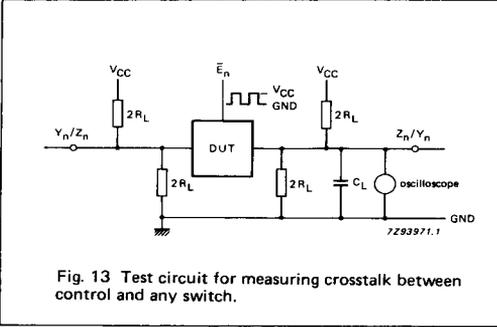


Fig. 13 Test circuit for measuring crosstalk between control and any switch.

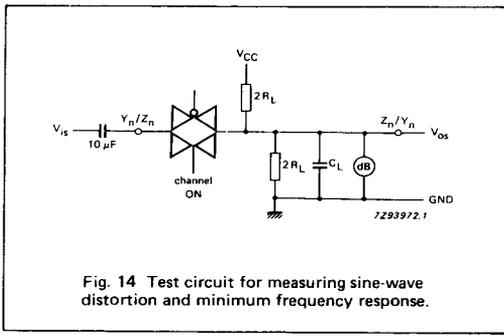
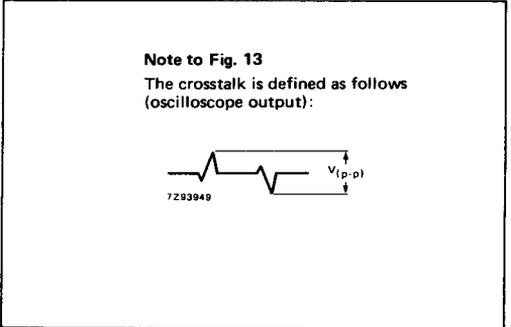


Fig. 14 Test circuit for measuring sine-wave distortion and minimum frequency response.

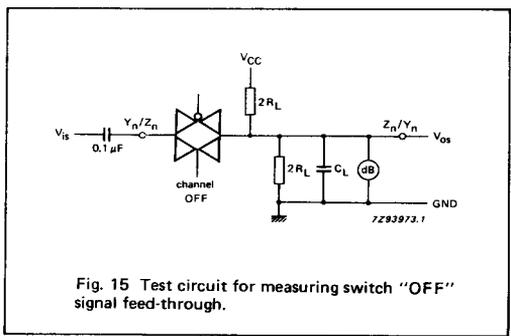
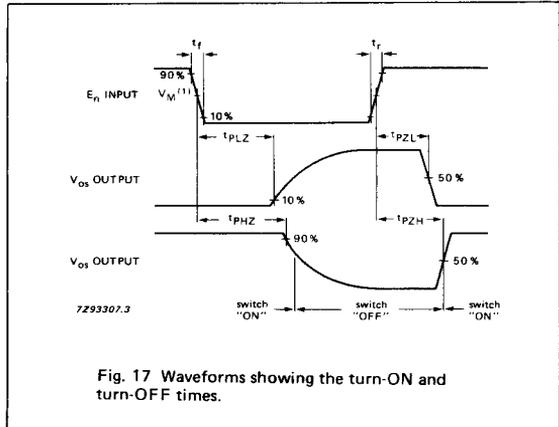
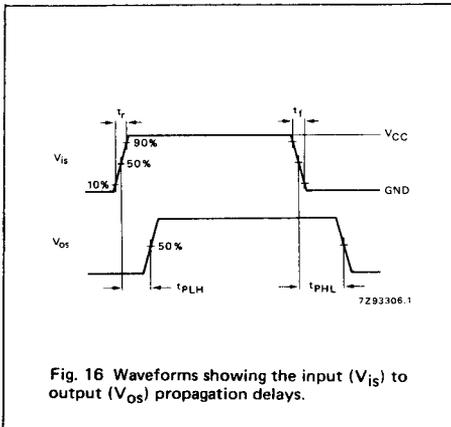


Fig. 15 Test circuit for measuring switch "OFF" signal feed-through.

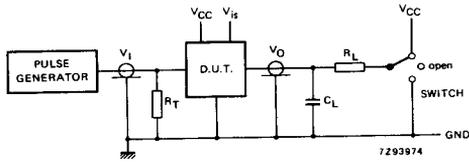
AC WAVEFORMS



Note to AC waveforms

- (1) HC :  $V_M = 50\%$ ;  $V_I = \text{GND to } V_{CC}$ .
- HCT:  $V_M = 1.3 \text{ V}$ ;  $V_I = \text{GND to } 3 \text{ V}$ .

TEST CIRCUIT AND WAVEFORMS



Conditions

TEST	SWITCH	V <sub>is</sub>
tpZH	GND	V <sub>CC</sub>
tpZL	V <sub>CC</sub>	GND
tpHZ	GND	V <sub>CC</sub>
tpLZ	V <sub>CC</sub>	GND
others	open	pulse

Fig. 18 Test circuit for measuring AC performance.

Definitions for Figs 18 and 19:

C<sub>L</sub> = load capacitance including jig and probe capacitance (see AC CHARACTERISTICS for values).

R<sub>T</sub> = termination resistance should be equal to the output impedance Z<sub>O</sub> of the pulse generator.

t<sub>r</sub> = t<sub>f</sub> = 6 ns; when measuring f<sub>max</sub>, there is no constraint on t<sub>r</sub>, t<sub>f</sub> with 50% duty factor.

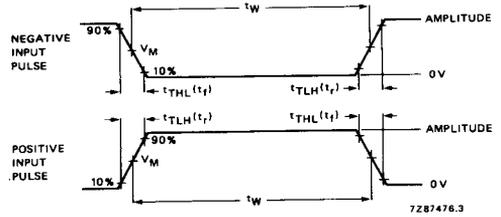


Fig. 19 Input pulse definitions.

FAMILY	AMPLITUDE	V <sub>M</sub>	t <sub>r</sub> ; t <sub>f</sub>	
			f <sub>max</sub> : PULSE WIDTH	OTHER
74HC	V <sub>CC</sub>	50%	< 2 ns	6 ns
74HCT	3.0 V	1.3 V	< 2 ns	6 ns